

Datasheet-production date

## Description

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications.



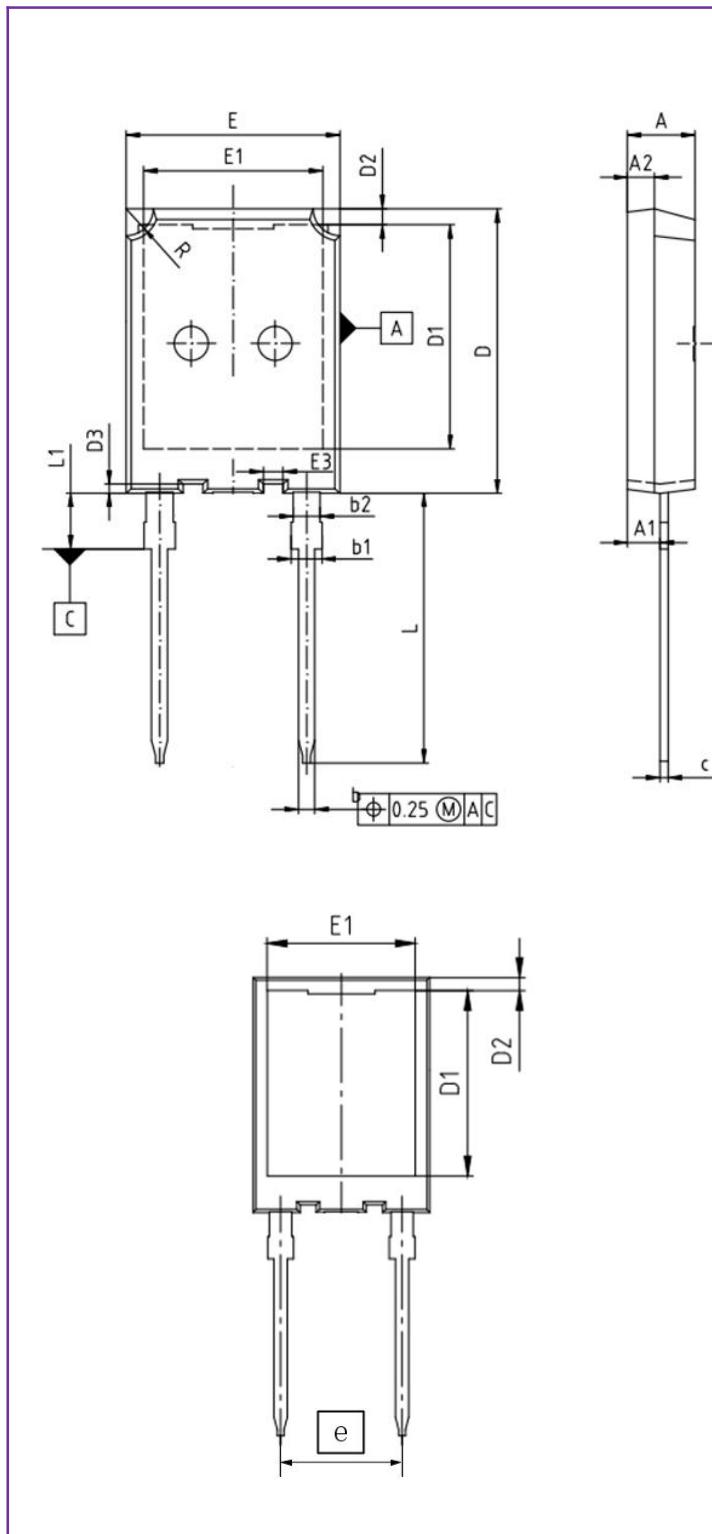
## Features

- ◆ Diffused diode
- ◆ High voltage ratings
- ◆ High surge current capabilities
- ◆ Designed and qualified for industrial level

## Applications

- ◆ Welders
- ◆ Power supplies
- ◆ Machine tool controls
- ◆ High power drives
- ◆ Medium traction applications
- ◆ Battery charges
- ◆ Freewheeling diodes

## Dimensions (TO-247PLUS)



Symbol	Dimension			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.90	5.10	0.193	0.201
A1	2.31	2.51	0.091	0.099
A2	1.90	2.10	0.075	0.083
b	1.16	1.26	0.046	0.050
b1	1.96	2.25	0.077	0.089
b2	1.96	2.06	0.077	0.081
c	0.59	0.66	0.023	0.026
D	20.90	21.10	0.823	0.831
D1	16.25	16.85	0.640	0.663
D2	1.05	1.35	0.041	0.053
D3	0.58	0.78	0.023	0.031
E	15.70	15.90	0.618	0.626
E1	13.10	13.50	0.516	0.531
E3	1.35	1.55	0.053	0.061
e	10.88 BSC		0.428 BSC	
L	19.80	20.10	0.780	0.791
L1	-	4.30	-	0.169
R	1.90	2.10	0.075	0.083

## Maximum Ratings and Electrical Characteristics( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Conditions			Min	Typ	Max	Unit
Peak repetitive reverse voltage	$V_R$					1000		V
Average forward current at case temperature@125°C	$I_{F(AV)}$	180° conduction, half sine wave				150		A
Repetitive Peak Surge Current (Square Wave, 20 kHz)	$I_{FRM}$					300		A
Maximum RMS forward current	$I_{F(RMS)}$	DC at 110°C				235		A
Maximum peak, one cycle forward, non-repetitive surge current	$I_{FSM}$	$t = 10 \text{ ms}$	No voltage reapplied	Sinusoidal half wave Initial $T_J = T_{Jmax}$		3000		A
Maximum $I^2t$ for fusing	$I^2t$	$t = 8.3 \text{ ms}$				3140		
		$t = 10 \text{ ms}$				45		$\text{kA}^2\text{s}$
		$t = 8.3 \text{ ms}$				41		
Slope resistance	$r_f$	$T_J = T_{Jmax}$				0.97		$\text{m } \Omega$
Threshold voltage	$V_{F(T0)}$					0.80		V
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 600 \text{ A}, T_J = 25^\circ C,$ $t_p = 10 \text{ ms}$ sinusoidal wave					1.47	V
Maximum junction operating and storage temperature range	$T_J, T_{STG}$				-40 to +180			$^\circ C$
Maximum Non-Repetitive Peak Reverse Voltage	$V_{RSM}$						1100	V
Reverse recovery time	$t_{rr}$	$I_F=0.5\text{A}, I_R=1\text{A}, I_{RR}=0.25\text{A}$					100	ns
Peak recovery current	$I_{RRM}$	$T_J = T_{Jmax}$					15	mA
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation					0.3	K/W
Maximum thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, flat, smooth and greased					0.1	

## Ratings and Characteristic Curves ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Figure 1. Current Ratings Characteristics

Figure 2. Current Ratings Characteristics

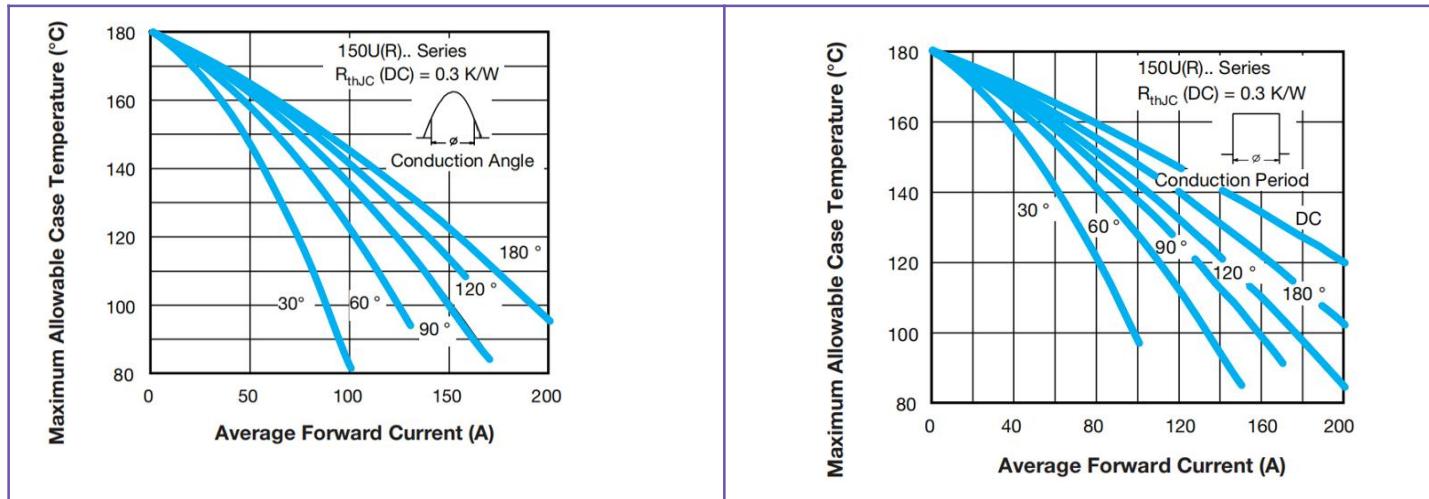


Figure 3. Forward Power Loss Characteristics

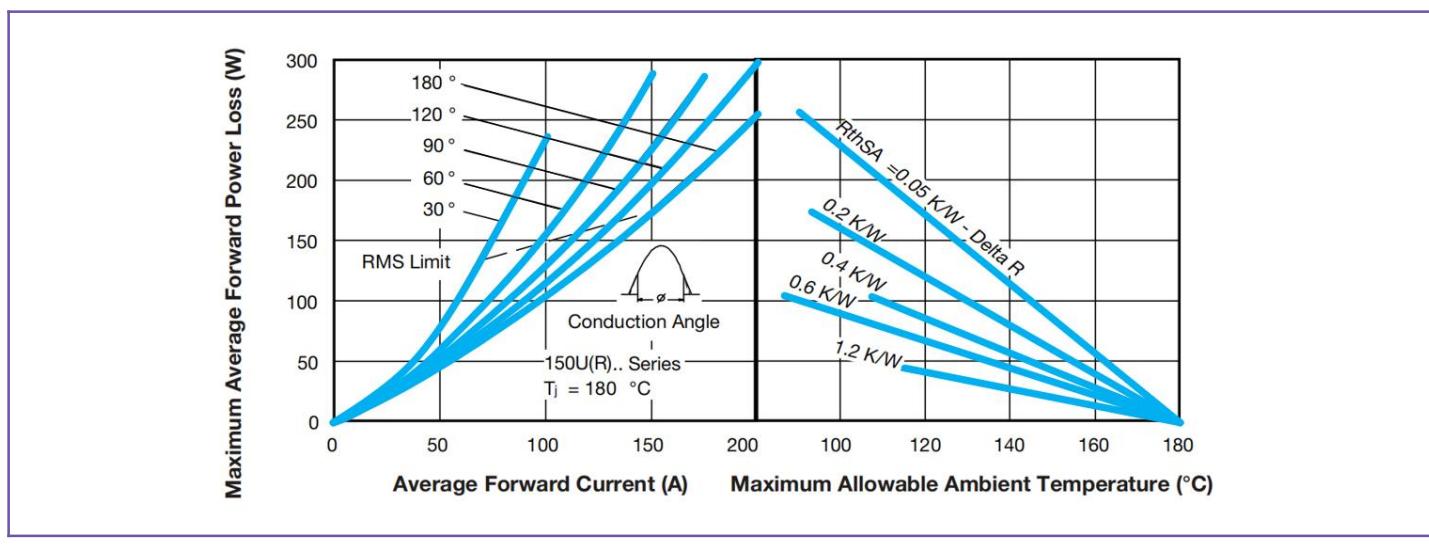


Figure 4. Forward Power Loss Characteristics

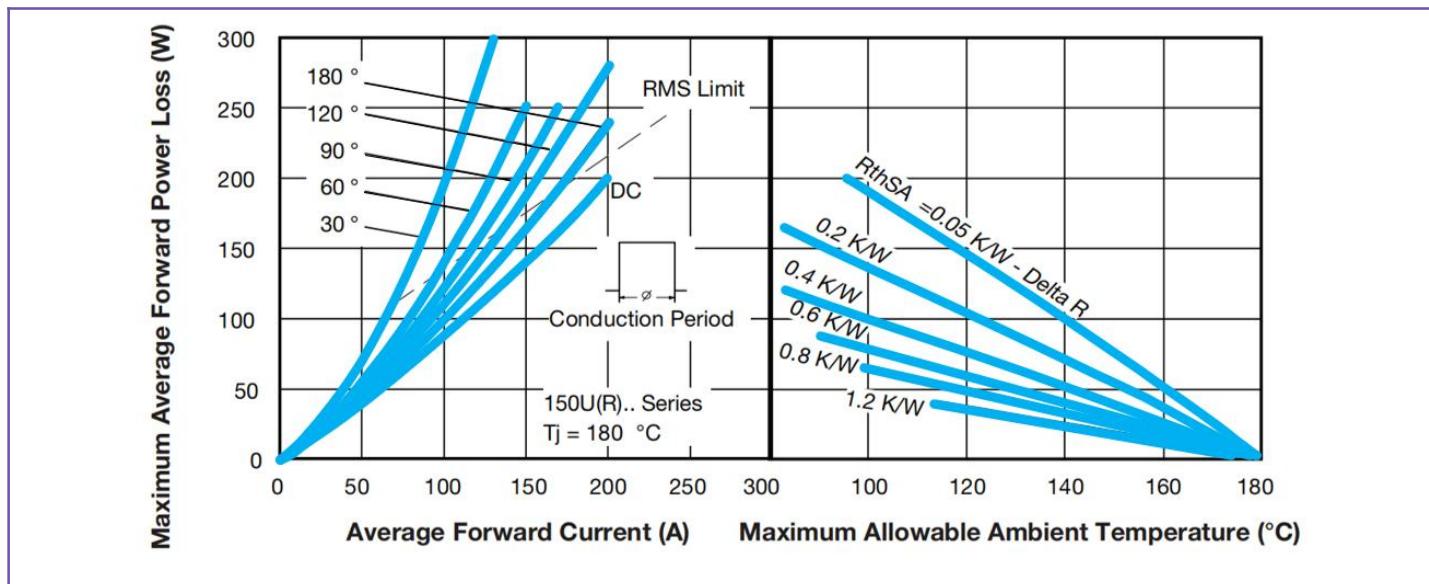


Figure 5. Maximum Non-Repetitive Surge Current

Figure 6. Maximum Non-Repetitive Surge Current

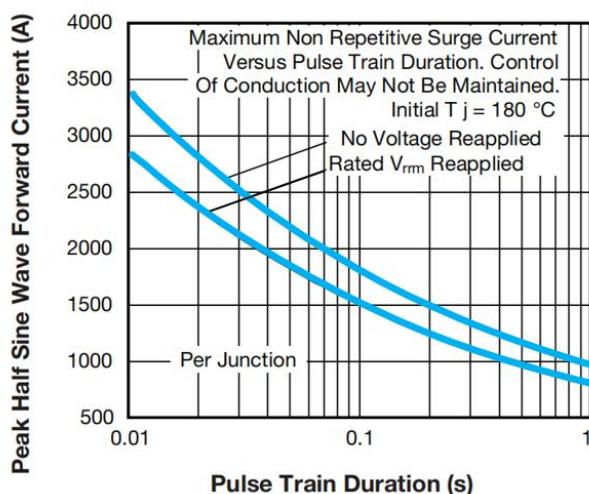
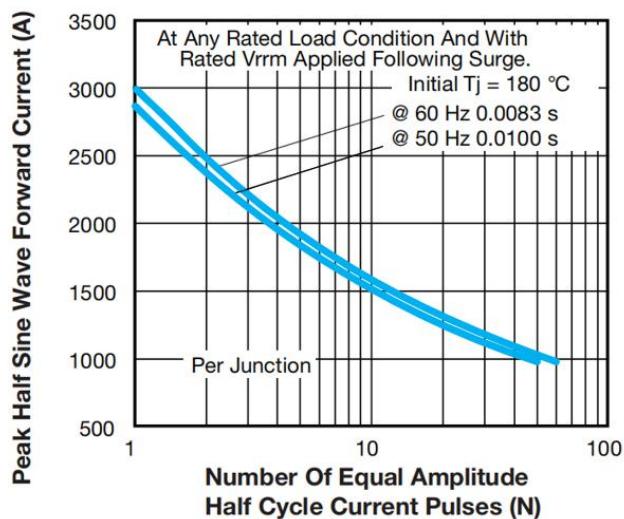
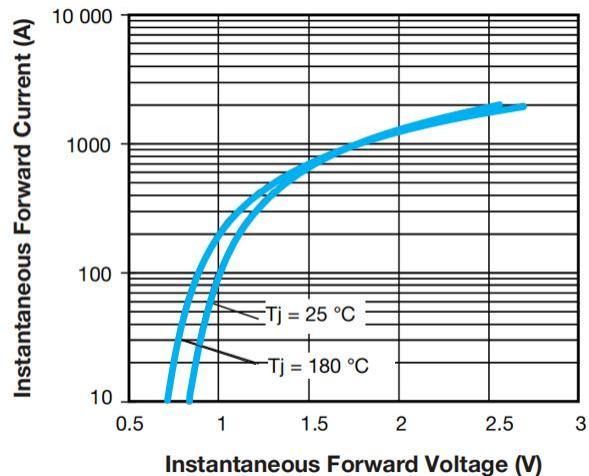
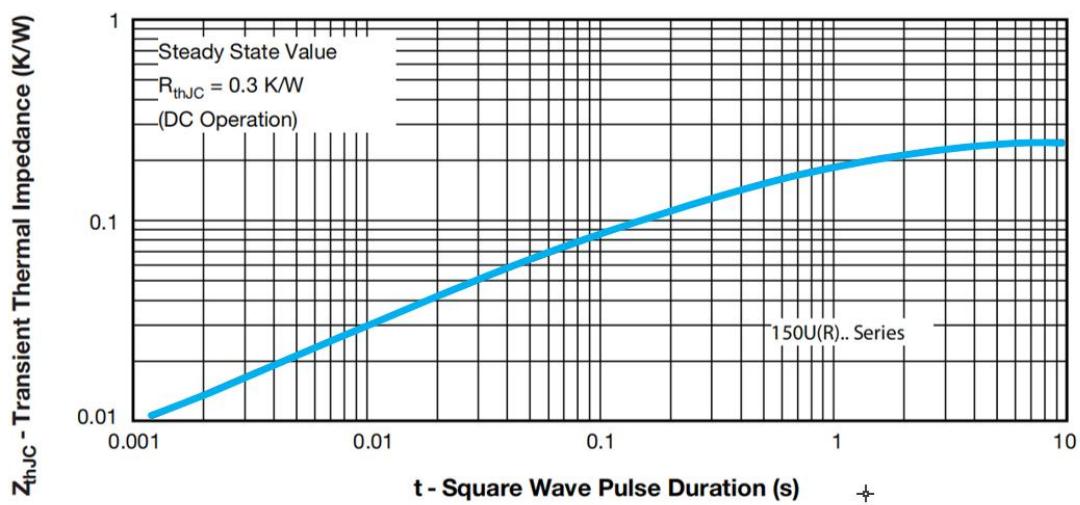


Figure 7. Forward Voltage Drop Characteristics

Figure 8. Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristic

## Wave Soldering Parameters

